



## Correction to: Electrical and optical characterizations of InAs/GaAs quantum dot solar cells

Im Sik Han<sup>1,5</sup> · Seung Hyun Kim<sup>1</sup> · Jong Su Kim<sup>1</sup> · Sam Kyu Noh<sup>2</sup> · Sang Jun Lee<sup>2</sup> · Honggyun Kim<sup>3</sup> · Deok-Kee Kim<sup>3</sup> · Jae-Young Leem<sup>4</sup>

Published online: 22 February 2018  
© Springer-Verlag GmbH Germany, part of Springer Nature 2018

**Correction to: Applied Physics A (2018) 124:245**  
<https://doi.org/10.1007/s00339-018-1661-y>

The original article was corrected.

The original version of this article unfortunately contained a mistake. The spelling of the 6th author was incorrect. The correct name is Honggyun Kim.

---

The original article can be found online at <https://doi.org/10.1007/s00339-018-1661-y>.

---

✉ Jong Su Kim  
jongsukim@ynu.ac.kr

<sup>1</sup> Department of Physics, Yeungnam University,  
Gyeongsan 38541, Republic of Korea

<sup>2</sup> Division of Convergence Technology, Korea Research  
Institute of Standards and Science, Daejeon 34113,  
Republic of Korea

<sup>3</sup> Department of Electrical Engineering, Sejong University,  
Seoul 05006, Republic of Korea

<sup>4</sup> School of Nano Engineering, Center for Nano  
Manufacturing, Inje University, Gimhae 50834,  
Republic of Korea

<sup>5</sup> Present Address: Department of Electronic and Electrical  
Engineering, University of Sheffield, Sheffield S1 3JD, UK